

C106A1 C106D1  
C106B1 C106E1  
C106C1 C106M1

**SILICON CONTROLLED RECTIFIER  
4 AMP, 100 THRU 600 VOLTS**



**TO-202 CASE**



[www.centra-semi.com](http://www.centra-semi.com)

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR C106A1 series are PNP silicon controlled rectifiers designed for applications such as temperature, light, speed control, process and remote control, and warning systems where reliability of operation is important.

**MARKING: FULL PART NUMBER**

**MAXIMUM RATINGS:** ( $T_C=25^\circ\text{C}$  unless otherwise noted)

	SYMBOL	C106 A1	C106 B1	C106 C1	C106 D1	C106 E1	C106 M1	UNITS
Peak Repetitive Off-State Voltage	$V_{DRM}, V_{RRM}$	100	200	300	400	500	600	V
RMS On-State Current	$I_{T(RMS)}$				4.0			A
Peak One Cycle Surge (60Hz)	$I_{TSM}$				20			A
$I^2t$ Value for Fusing ( $t > 1.5\text{ms}$ )	$I^2t$				0.5			$\text{A}^2\text{s}$
Peak Gate Power	$P_{GM}$				0.5			W
Average Gate Power	$P_{G(AV)}$				0.1			W
Peak Forward Gate Current	$I_{GFM}$				0.2			A
Peak Reverse Gate Voltage	$V_{GRM}$				6.0			V
Storage Temperature	$T_{stg}$				-40 to +150			$^\circ\text{C}$
Junction Temperature	$T_J$				-40 to +110			$^\circ\text{C}$
Thermal Resistance	$\theta_{JC}$				3.0			$^\circ\text{C/W}$
Thermal Resistance	$\theta_{JA}$				75			$^\circ\text{C/W}$

**ELECTRICAL CHARACTERISTICS:** ( $T_C=25^\circ\text{C}$  unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
$I_{DRM}, I_{RRM}$	Rated $V_{DRM}, V_{RRM}, R_{GK}=1.0\text{K}\Omega$			10	$\mu\text{A}$
$I_{DRM}, I_{RRM}$	Rated $V_{DRM}, V_{RRM}, R_{GK}=1.0\text{K}\Omega, T_C=110^\circ\text{C}$			100	$\mu\text{A}$
$V_{TM}$	$I_{FM}=4.0\text{A}$			2.2	V
$I_{GT}$	$V_{AK}=6.0\text{V}, R_L=100\Omega, R_{GK}=1.0\text{K}\Omega$			200	$\mu\text{A}$
$I_{GT}$	$V_{AK}=6.0\text{V}, R_L=100\Omega, R_{GK}=1.0\text{K}\Omega, T_C=-40^\circ\text{C}$			500	$\mu\text{A}$
$V_{GT}$	$V_{AK}=6.0\text{V}, R_L=100\Omega, R_{GK}=1.0\text{K}\Omega$	0.4		0.8	V
$V_{GT}$	$V_{AK}=6.0\text{V}, R_L=100\Omega, R_{GK}=1.0\text{K}\Omega, T_C=-40^\circ\text{C}$	0.5		1.0	V
$V_{GT}$	$V_{AK}=\text{Rated } V_{DRM}, R_L=3.0\text{K}\Omega, R_{GK}=1.0\text{K}\Omega, T_C=110^\circ\text{C}$	0.2			V
$I_{HX}$	$V_D=12\text{V}, R_{GK}=1.0\text{K}\Omega$	0.3		3.0	mA
$I_{HX}$	$V_D=12\text{V}, R_{GK}=1.0\text{K}\Omega, T_C=-40^\circ\text{C}$	0.4		6.0	mA
$I_{HX}$	$V_D=12\text{V}, R_{GK}=1.0\text{K}\Omega, T_C=110^\circ\text{C}$	0.14		2.0	mA
$I_{LX}$	$V_D=12\text{V}, R_{GK}=1.0\text{K}\Omega$	0.3		4.0	mA
$I_{LX}$	$V_D=12\text{V}, R_{GK}=1.0\text{K}\Omega, T_C=-40^\circ\text{C}$	0.4		8.0	mA
$dv/dt$	$V_D=\text{Rated } V_{DRM}, R_{GK}=1.0\text{K}\Omega, T_C=110^\circ\text{C}$		8.0		$\text{V}/\mu\text{s}$
$t_{gt}$ (turn-on time)			1.2		$\mu\text{s}$
$t_q$ (turn-off time)			40		$\mu\text{s}$

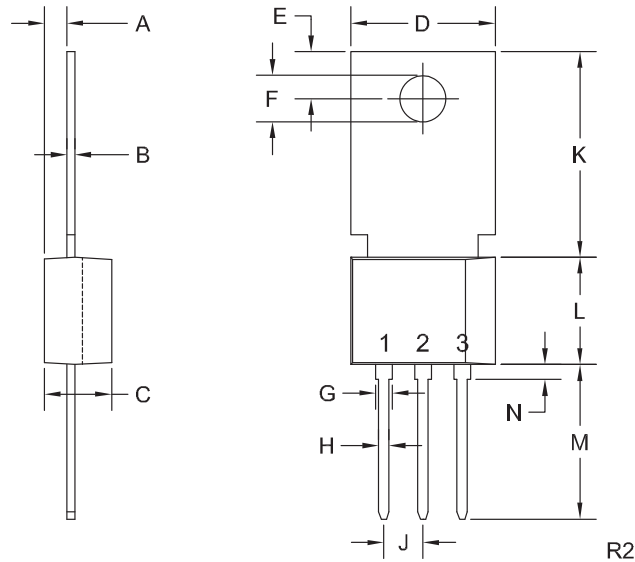
R1 (23-January 2012)

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**TO-202 CASE - MECHANICAL OUTLINE**



**LEAD CODE:**

- 1) Cathode
- 2) Anode
- 3) Gate
- Tab is common to pin 2

**MARKING:**

**FULL PART NUMBER**

DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.055	0.071	1.40	1.80
B	0.016	0.024	0.40	0.60
C	0.173	0.181	4.40	4.60
D	0.374	0.413	9.50	10.5
E	0.118	0.154	3.00	3.90
F (DIA)	0.124	0.150	3.15	3.80
G	0.035	0.055	0.90	1.40
H	0.023	0.031	0.59	0.80
J	0.094	0.106	2.39	2.69
K	0.459	0.559	11.66	14.21
L	0.280	0.346	7.12	8.80
M	0.406	0.531	10.3	13.5
N	0.024	0.059	0.60	1.50

TO-202 (REV: R2)

R1 (23-January 2012)

## OUTSTANDING SUPPORT AND SUPERIOR SERVICES



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### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

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### DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

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### REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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### CONTACT US

#### Corporate Headquarters & Customer Support Team

Central Semiconductor Corp.  
145 Adams Avenue  
Hauppauge, NY 11788 USA  
Main Tel: (631) 435-1110  
Main Fax: (631) 435-1824  
Support Team Fax: (631) 435-3388  
[www.centrasemi.com](http://www.centrasemi.com)

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[www.centrasemi.com/wwreps](http://www.centrasemi.com/wwreps)

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